NSN 5962-01-414-5534

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View Online at https://aerobasegroup.com/nsn/5962-01-414-5534

Body Length:

0.460 inches

Body Width:

0.460 inches

Body Height:

0.100 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Pacer dawn

Features Provided:

Electrostatic sensitive and monolithic and tested to mil-std-883

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Criticality Code Justification:

Feat

Case Outline Source And Designator:

C-4 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuits, digital, cmos 4k x4 sram with separate i/o monolithic s-ilicon

Voltage Rating And Type Per Characteristic:

4.5 volts total supply and 5.5 volts total supply

Time Rating Per Chacteristic:

45.00 nanoseconds access

Memory Device Type:

Ram

Special Features:

Esd

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 leadless

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A458a0

